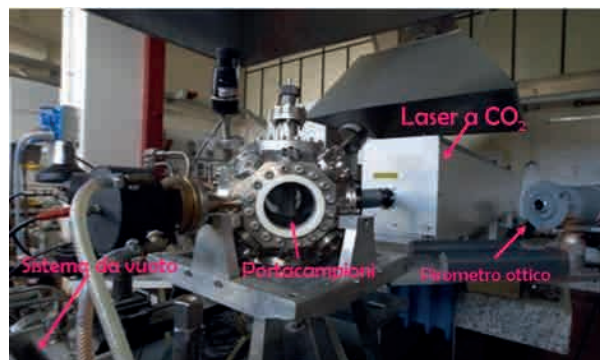
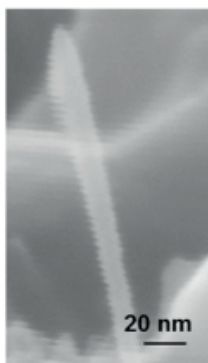
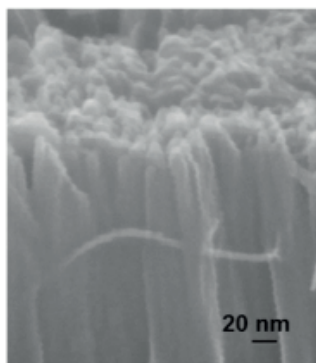
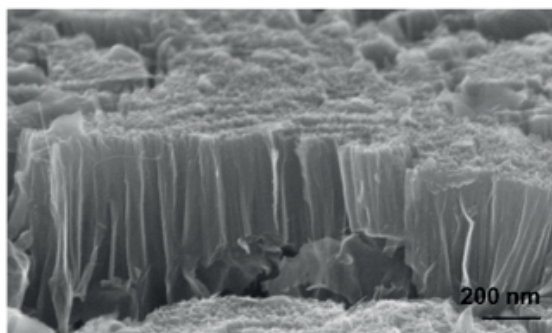


# GROWTH OF NANO-CARBON ARCHITECTURES ON SiC

**Innovations and Benefits** - The carbon nano-structures grow from SiC by CO<sub>2</sub> laser annealing of SiC, without using metal catalyst, therefore this process does not require further chemical purification treatments.

**Use** - By varying the process parameters, it is possible to obtain different carbon nano-structures. Carbon-nanotubes, which grow with an orthogonal orientation respect to the substrate, can be used as miniaturized electron emitters.

**Applications and ongoing Activities** - Optimization of process parameters to control the nano-tube growth. Study of conditions to obtain mono-layer graphene.



#### Riferimenti:

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